MOSFET – Dual, N-Channel, Small Signal, SOT-963, 1.0 mm x 1.0 mm

20 V, 220 mA

Features

- Dual N-Channel MOSFET
- Offers a Low $R_{DS(ON)}$ Solution in the Ultra Small 1.0 x 1.0 mm Package
- 1.5 V Gate Voltage Rating
- Ultra Thin Profile (< 0.5 mm) Allows It to Fit Easily into Extremely Thin Environments such as Portable Electronics
- This is a Pb–Free Device

Applications

- General Purpose Interfacing Switch
- Optimized for Power Management in Ultra Portable Equipment
- Analog Switch

MAXIMUM RATINGS (T_J = 25° C unless otherwise specified)

Para	meter		Symbol	Value	Unit
Drain-to-Source Voltag	je		V _{DSS}	20	V
Gate-to-Source Voltag	Gate-to-Source Voltage		V _{GS}	±8	V
Continuous Drain	Steady State	$T_A = 25^{\circ}C$	ID	220	
Current (Note 1)		$T_A = 85^{\circ}C$		160	mA
	t ≤ 5 s	$T_A = 25^{\circ}C$		280	
Power Dissipation	Steady			125	
(Note 1)	State	State $T_A = 25^{\circ}C$ P_D	PD		mW
	t ≤ 5 s			200	
Pulsed Drain Current		t _p = 10 μs	I _{DM} 800		mA
Operating Junction and	perating Junction and Storage Temperature		_T_J,	-55 to	°C
			T _{STG}	150	
Source Current (Body D	Diode) (Note 2	<u>2)</u>	I _S 200		mA
Lead Temperature for S (1/8" from case for 1		oses	ΤL	260	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Surface-mounted on FR4 board using the minimum recommended pad size, 1 oz Cu.

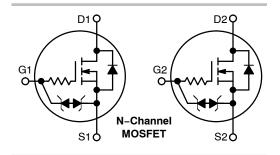
2. Pulse Test: pulse width \leq 300 μ s, duty cycle \leq 2%



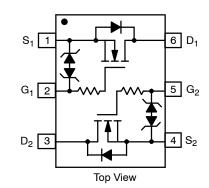
ON Semiconductor®

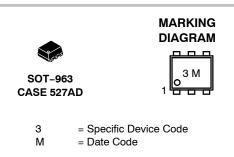
www.onsemi.com

V _{(BR)DSS}	R _{DS(ON)} MAX	I _D Max
	1.5 Ω @ 4.5 V	
20 V	2.0 Ω @ 2.5 V	0.22 A
	3.0 Ω @ 1.8 V	
	4.5 Ω @ 1.5 V	



PINOUT: SOT-963





ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 2 of this data sheet.

THERMAL RESISTANCE RATINGS

Parameter	Symbol	Мах	Unit
Junction-to-Ambient – Steady State (Note 3)	R _{θJA}	1000	°C/W
Junction-to-Ambient – t = 5 s (Note 3)	ΓιθJΑ	600	0/11

3. Surface-mounted on FR4 board using the minimum recommended pad size, 1 oz Cu.

ELECTRICAL CHARACTERISTICS ($T_J = 25^{\circ}C$ unless otherwise specified)

Parameter	Symbol	Test Condition		Min	Тур	Max	Unit
OFF CHARACTERISTICS							
Drain-to-Source Breakdown Voltage	V _{(BR)DSS}	V_{GS} = 0 V, I _D = 250 µA		20			V
Zero Gate Voltage Drain Current			$T_J = 25^{\circ}C$			50	nA
	I _{DSS}	V_{GS} = 0 V, V_{DS} = 5 V	$T_J = 85^{\circ}C$			200	
		V_{GS} = 0 V, V_{DS} = 16 V	$T_J = 25^{\circ}C$			100	nA
Gate-to-Source Leakage Current	I _{GSS}	V_{DS} = 0 V, V_{GS} =	±5.0 V			±100	nA
ON CHARACTERISTICS (Note 4)							
Gate Threshold Voltage	V _{GS(TH)}	$V_{GS} = V_{DS}, I_D = 250 \ \mu A$		0.4		1.0	V
Drain-to-Source On Resistance		$V_{GS} = 4.5 \text{ V}, \text{ I}_{D} = 100 \text{ mA}$			0.75	1.5	Ω
		$V_{GS} = 2.5 \text{ V}, \text{ I}_{D} = 50 \text{ mA}$			1.0	2.0	
	R _{DS(ON)}	V_{GS} = 1.8 V, I _D = 20 mA			1.4	3.0	
		V _{GS} = 1.5 V, I _D = 10 mA			1.8	4.5	
		V_{GS} = 1.2 V, I _D = 1.0 mA			2.8		
Forward Transconductance	9 FS	V _{DS} = 5.0 V, I _D = 125 mA			0.48		S
Source-Drain Diode Voltage	V _{SD}	V_{GS} = 0 V, I_S = 10 mA			0.6	1.0	V
CAPACITANCES							
Input Capacitance	C _{ISS}	f = 1.0 MHz, V _{GS} = 0 V V _{DS} = 15 V			12.5		
Output Capacitance	C _{OSS}				3.6		pF
Reverse Transfer Capacitance	C _{RSS}				2.6		1
SWITCHING CHARACTERISTICS, V_{GS} =	4.5 V (Note 4)						
Turn-On Delay Time	t _{d(ON)}	$V_{GS} = 4.5 \text{ V}, V_{DD} = 10 \text{ V}, \text{I}_{D} = 200 \text{ mA}, \\ $			16.5		
Rise Time	t _r				25.5		ns
Turn-Off Delay Time	t _{d(OFF)}				142		
Fall Time	t _f				80		

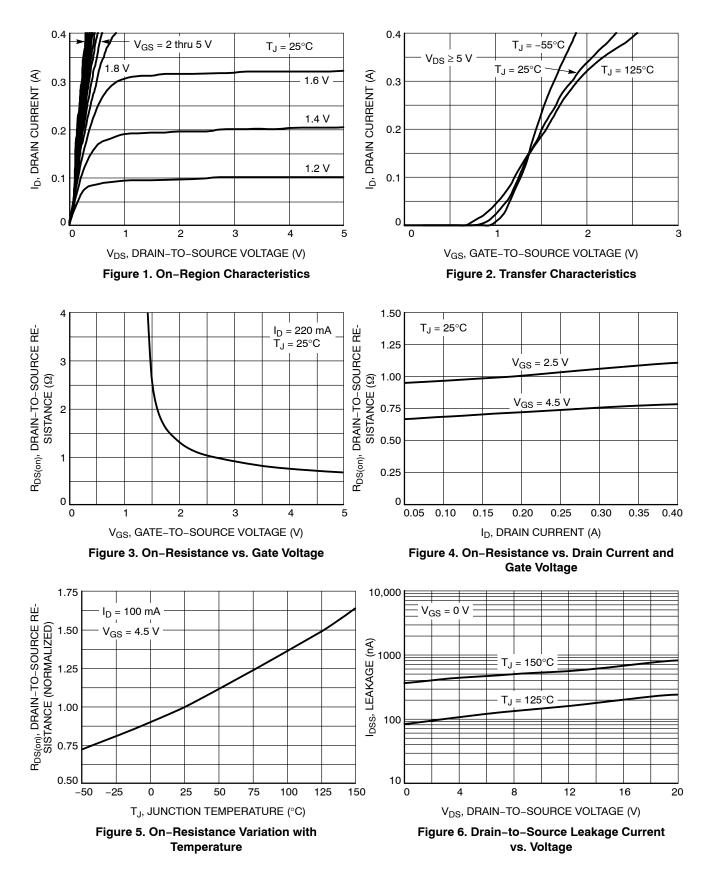
4. Switching characteristics are independent of operating junction temperatures.

ORDERING INFORMATION

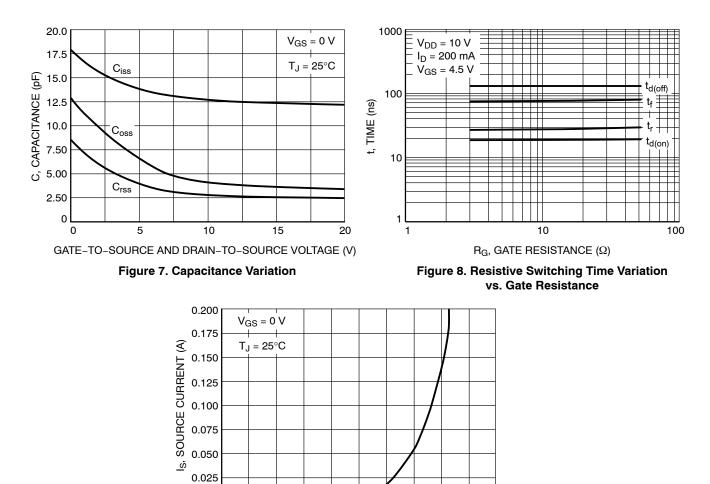
Device	Package	Shipping [†]
NTUD3170NZT5G	SOT-963 (Pb-Free)	8000 / Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

TYPICAL CHARACTERISTICS



TYPICAL CHARACTERISTICS



0.6

0.8

1

0.4

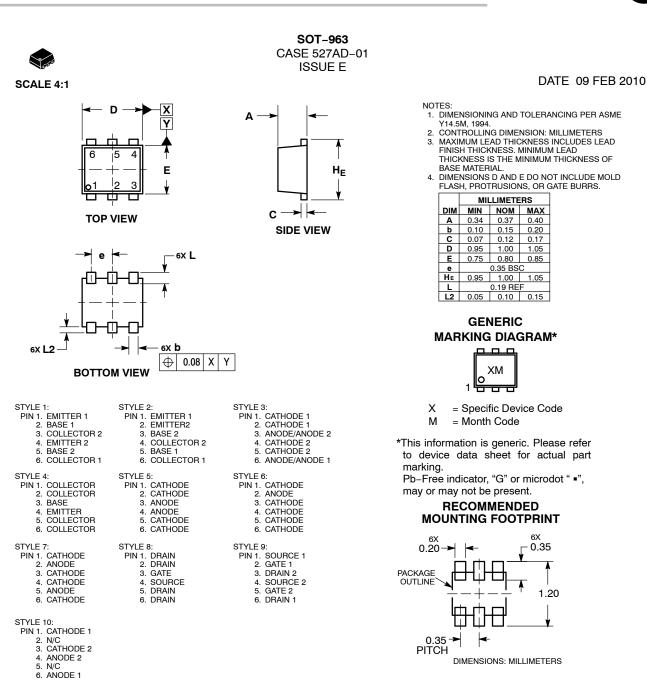
V_{SD}, SOURCE-TO-DRAIN VOLTAGE (V) Figure 9. Diode Forward Voltage vs. Current

0

0

0.2





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